



isc Silicon NPN Power Transistor

DESCRIPTION

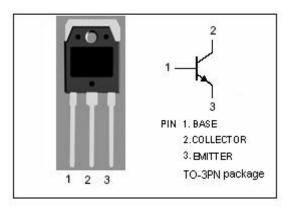
- · High Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 400V(Min)
- · High Switching Speed
- · High Reliability
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

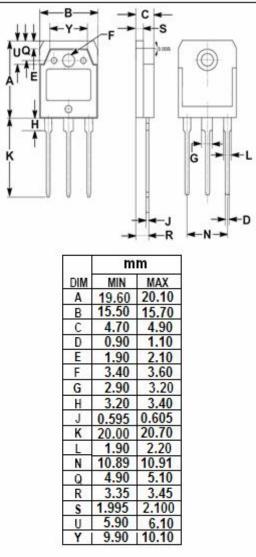


 Designed for switching regulator and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	500	V	
Vceo	Collector-Emitter Voltage	400	V	
V _{EBO}	Emitter-Base voltage	10	V	
Ic	Collector Current-Continuous	15	А	
Ісм	Collector Current-Peak(Pulse)	30	A	
I _B	Base Current-Continuous	5	А	
Pc	Collector Power Dissipation @ T _C =25℃	120	W	
TJ	Junction Temperature	150	$^{\circ}$ C	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$ C	







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2SC4139

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

16-25 C uniess otherwise specified								
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 25mA ; I _B = 0	400			V		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 8A; I _B = 1.6A			0.5	V		
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 8A; I _B = 1.6A			1.3	V		
I _{CBO}	Collector Cutoff Current	V _{CB} = 500V ; I _E = 0			0.1	mA		
ІЕВО	Emitter Cutoff Current	V _{EB} = 10V; I _C = 0			0.1	mA		
h _{FE}	DC Current Gain	I _C = 8A ; V _{CE} = 4V	10		30			
Сов	Output Capacitance	I _E = 0 ; V _{CB} = 10V; f _{test} =1.0MHz		85		pF		
f⊤	Current-Gain—Bandwidth Product	I _E = -1.5A ; V _{CE} = 12V		10		MHz		
Switching Times								
ton	Turn-on Time				1.0	μS		
t _{stg}	Storage Time	I _C = 8A,I _{B1} = 0.8A; I _{B2} = -1.6A R _L = 25 Ω; V _{CC} = 200V			3.0	μs		
t _f	Fall Time				0.5	μ S		

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